19-2724; Rev 0; 4/03

# 捷多邦,专业PCB打样工厂,24小时加急出货

# 250ksps, +3V, 8-/4-Channel, 10-Bit ADCs with +2.5V Reference and Parallel Interface

## **General Description**

The MAX1061/MAX1063 low-power, 10-bit analog-todigital converters (ADCs) feature a successive-approximation ADC, automatic power-down, fast wake-up (2µs), an on-chip clock, +2.5V internal reference, and a high-speed, byte-wide parallel interface. They operate with a single +3V analog supply and feature a V<sub>LOGIC</sub> pin that allows them to interface directly with a +1.8V to +3.6V digital supply.

Power consumption is only 5.7mW (V<sub>DD</sub> = V<sub>LOGIC</sub>) at the maximum sampling rate of 250ksps. Two softwareselectable power-down modes enable the MAX1061/ MAX1063 to be shut down between conversions; accessing the parallel interface returns them to normal operation. Powering down between conversions can cut supply current to under 10 $\mu$ A at reduced sampling rates.

Both devices offer software-configurable analog inputs for unipolar/bipolar and single-ended/pseudo-differential operation. In single-ended mode, the MAX1061 has eight input channels and the MAX1063 has four input channels (four and two input channels, respectively, when in pseudo-differential mode).

Excellent dynamic performance and low power, combined with ease of use and small package size, make these converters ideal for battery-powered and dataacquisition applications or for other circuits with demanding power consumption and space requirements.

The MAX1061 is available in a 28-pin QSOP package, while the MAX1063 is available in a 24-pin QSOP. For pin-compatible +5V, 10-bit versions, refer to the MAX1060/MAX1064 data sheet.

	Applications
Industrial Control Systems	Data Logging
Energy Management	Patient Monitoring
Data-Acquisition Systems	Touch Screens

<b>Ordering Information</b>
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PART	TEMP RANGE	PIN-PACKAGE	INL (LSB)
MAX1061ACEI	0°C to +70°C	28 QSOP	±0.5
MAX1061BCEI	0°C to +70°C	28 QSOP	±1
MAX1061AEEI	-40°C to +85°C	28 QSOP	±0.5
MAX1061BEEI	-40°C to +85°C	28 QSOP	±1

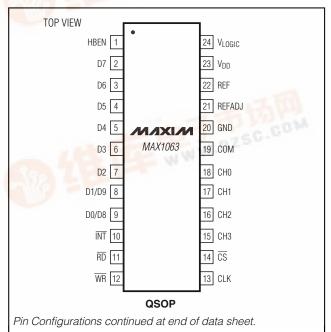
Ordering Information continued at end of data sheet.

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**Features** 

- 10-Bit Resolution, ±0.5 LSB Linearity
- +3V Single-Supply Operation
- User-Adjustable Logic Level (+1.8V to +3.6V)
- Internal +2.5V Reference
- Software-Configurable, Analog Input Multiplexer 8-Channel Single Ended/ 4-Channel Pseudo-Differential (MAX1061) 4-Channel Single Ended/ 2-Channel Pseudo-Differential (MAX1063)
- Software-Configurable, Unipolar/Bipolar Inputs
- Low Power
  - 1.9mA (250ksps) 1.0mA (100ksps) 400μA (10ksps) 2μA (Shutdown)
- Internal 3MHz Full-Power Bandwidth Track/Hold
- Byte-Wide Parallel (8 + 2) Interface
- Small Footprint: 28-Pin QSOP (MAX1061) 24-Pin QSOP (MAX1063)

## **Pin Configurations**



Typical Operating Circuits appear at end of data sheet.

Maxim Integrated Products 1

<sup>P</sup>For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at

## **ABSOLUTE MAXIMUM RATINGS**

V <sub>DD</sub> to GND	
VLOGIC to GND	
CH0-CH7, COM to GND	0.3V to (V <sub>DD</sub> + 0.3V)
REF, REFADJ to GND	0.3V to (V <sub>DD</sub> + 0.3V)
Digital Inputs to GND	
Digital Outputs (D0–D9, INT) to GND	0.3V to (VLOGIC + 0.3V)

Continuous Power Dissipation ( $T_A = +70^{\circ}C$ )
24-Pin QSOP (derate 9.5mW/°C above +70°C)762mW
28-Pin QSOP (derate 8.0mW/°C above +70°C)667mW
Operating Temperature Ranges
MAX1061_C/MAX1063_C0°C to +70°C
MAX1061_E/MAX1063_E40°C to +85°C
Storage Temperature Range65°C to +150°C
Lead Temperature (soldering, 10s)+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS

 $(V_{DD} = V_{LOGIC} = +2.7V \text{ to } +3.6V, \text{COM} = \text{GND}, \text{REFADJ} = V_{DD}, V_{REF} = +2.5V, 4.7\mu\text{F}$  capacitor at REF pin, f<sub>CLK</sub> = 4.8MHz (50% duty cycle), T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise noted. Typical values are at T<sub>A</sub> = +25°C.)

PARAMETER	SYMBOL	CONDITIONS	MIN	ΤΥΡ	MAX	UNITS
DC ACCURACY (Note 1)	-1	-				
Resolution	RES		10			Bits
Polotivo Apouropy (Noto 2)	INL	MAX106_A			±0.5	LSB
Relative Accuracy (Note 2)		MAX106_B			±1	LSB
Differential Nonlinearity	DNL	No missing codes over temperature			±1	LSB
Offset Error					±2	LSB
Gain Error		(Note 3)			±2	LSB
Gain Temperature Coefficient				±2.0		ppm/°C
Channel-to-Channel Offset Matching				±0.1		LSB
DYNAMIC SPECIFICATIONS (fin	v(sine wave) =	= 50kHz, VIN = 2.5Vp-p, 250ksps, external fCLK =	4.8MHz, 1	pipolar inp	out mode)	)
Signal-to-Noise Plus Distortion	SINAD			60		dB
Total Harmonic Distortion (Including 5th-Order Harmonic)	THD			-72		dB
Spurious-Free Dynamic Range	SFDR			72		dB
Intermodulation Distortion	IMD	$f_{IN1} = 49$ kHz, $f_{IN2} = 52$ kHz		76		dB
Channel-to-Channel Crosstalk		f <sub>IN</sub> = 125kHz, V <sub>IN</sub> = 2.5V <sub>P-P</sub> (Note 4)		-78		dB
Full-Linear Bandwidth		SINAD > 56dB		250		kHz
Full-Power Bandwidth		-3dB rolloff		3		MHz
CONVERSION RATE						
		External clock mode	3.3			
Conversion Time (Note 5)	tCONV	External acquisition/internal clock mode	2.5	3.0	3.5	μs
		Internal acquisition/internal clock mode	3.2	3.6	4.1	
Track/Hold Acquisition Time	tacq				625	ns
Aperture Delay		External acquisition or external clock mode		50		ns
Aperture Jitter		External acquisition or external clock mode		<50		ps
•		Internal acquisition/internal clock mode		<200		
External Clock Frequency	fCLK		0.1		4.8	MHz
Duty Cycle			30		70	%



## **ELECTRICAL CHARACTERISTICS (continued)**

 $(V_{DD} = V_{LOGIC} = +2.7V \text{ to } +3.6V, \text{COM} = \text{GND}, \text{REFADJ} = V_{DD}, V_{REF} = +2.5V, 4.7\mu\text{F}$  capacitor at REF pin, f<sub>CLK</sub> = 4.8MHz (50% duty cycle), T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise noted. Typical values are at T<sub>A</sub> = +25°C.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
ANALOG INPUTS							
Analog Input Voltage Range Single Ended and Differential	VIN	Unipolar, V <sub>COM</sub> = 0	0		V <sub>REF</sub>	V	
(Note 6)		Bipolar, V <sub>COM</sub> = V <sub>REF</sub> / 2	-V <sub>REF</sub> /2		$+V_{REF}/2$		
Multiplexer Leakage Current		On-/off-leakage current, VIN = 0 or VDD		±0.01	±1	μA	
Input Capacitance	CIN			12		pF	
INTERNAL REFERENCE			I				
REF Output Voltage			2.49	2.5	2.51	V	
REF Short-Circuit Current				15		mA	
REF Temperature Coefficient	TC <sub>REF</sub>	$T_A = 0^{\circ}C \text{ to } +70^{\circ}C$		±20		ppm/°C	
REFADJ Input Range		For small adjustments		±100		mV	
REFADJ High Threshold		To power down the internal reference	V <sub>DD</sub> - 1.0			V	
Load Regulation		0 to 0.5mA output load (Note 7)		0.2		mV/m/	
Capacitive Bypass at REFADJ				0.01	1	μF	
Capacitive Bypass at REF			4.7		10	μF	
EXTERNAL REFERENCE AT R	EF		·				
REF Input Voltage Range	V <sub>REF</sub>		1.0		V <sub>DD</sub> + 50mV	V	
REF Input Current	lass	V <sub>REF</sub> = 2.5V, f <sub>SAMPLE</sub> = 250ksps		200	300	μA	
ner input Current	IREF	Shutdown mode			2		
DIGITAL INPUTS AND OUTPU	rs		·				
Input High Voltage	VIH	$V_{LOGIC} = 2.7V$	2.0			V	
input high voltage	VН	$V_{LOGIC} = 1.8V$	1.5			v	
Input Low Voltage	VIL	$V_{LOGIC} = 2.7V$			0.8	V	
Input Low Voltage	VIL	$V_{LOGIC} = 1.8V$			0.5	v	
Input Hysteresis	V <sub>HYS</sub>			200		mV	
Input Leakage Current	l <sub>IN</sub>	$V_{IN} = 0 \text{ or } V_{DD}$		±0.1	±1	μA	
Input Capacitance	CIN			15		pF	
Output Low Voltage	Vol	I <sub>SINK</sub> = 1.6mA			0.4	V	
Output High Voltage	V <sub>OH</sub>	I <sub>SOURCE</sub> = 1mA	VLOGIC -	0.5		V	
Tri-State Leakage Current	ILEAKAGE	$\overline{\text{CS}} = \text{V}_{\text{DD}}$		±0.1	±1	μA	
Tri-State Output Capacitance	COUT	$\overline{\text{CS}} = \text{V}_{\text{DD}}$		15		pF	

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## ELECTRICAL CHARACTERISTICS (continued)

 $(V_{DD} = V_{LOGIC} = +2.7V \text{ to } +3.6V, \text{COM} = \text{GND}, \text{REFADJ} = V_{DD}, V_{REF} = +2.5V, 4.7\mu\text{F} \text{ capacitor at REF pin, } f_{CLK} = 4.8MHz (50\% duty cycle), T_A = T_{MIN} \text{ to } T_{MAX}$ , unless otherwise noted. Typical values are at T\_A = +25°C.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS		
POWER REQUIREMENTS	POWER REQUIREMENTS								
Analog Supply Voltage	V <sub>DD</sub>			2.7		3.6	V		
Digital Supply Voltage	VLOGIC			1.8	V	D + 0.3	V		
Positive Supply Current IDD		Operating mode,	Internal reference		2.3	2.6			
		fsample = 250ksps	External reference		1.9	2.3	- mA		
	IDD	Standby mode	Internal reference		0.9	1.2			
			External reference		0.5	0.8			
		Shutdown mode			2	10	μA		
Mussie Current		0 00-5	f <sub>SAMPLE</sub> = 250ksps			150			
VLOGIC Current	ILOGIC		CL = 20pF Not converting		2	10	μΑ		
Power-Supply Rejection	PSR	$V_{DD} = 3V \pm 10\%$ , full-s	scale input		±0.4	±0.9	mV		

## **TIMING CHARACTERISTICS**

 $(V_{DD} = V_{LOGIC} = +2.7V \text{ to } +3.6V, \text{ COM} = \text{GND}, \text{REFADJ} = V_{DD}, V_{REF} = +2.5V, 4.7\mu\text{F} \text{ capacitor at REF pin}, f_{CLK} = 4.8MHz$  (50% duty cycle),  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. Typical values are at  $T_A = +25^{\circ}\text{C}$ .)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
CLK Period	tCP		208			ns
CLK Pulse Width High	tсн		40			ns
CLK Pulse Width Low	t <sub>CL</sub>		40			ns
Data Valid to WR Rise Time	tDS		40			ns
WR Rise to Data Valid Hold Time	tDH		0			ns
WR to CLK Fall Setup Time	tcws		40			ns
CLK Fall to WR Hold Time	tCMH		40			ns
CS to CLK or WR Setup Time	tcsws		60			ns
CLK or $\overline{WR}$ to $\overline{CS}$ Hold Time	t <sub>CSWH</sub>		0			ns
CS Pulse Width	tcs		100			ns
WR Pulse Width	twR	(Note 8)	60			ns
CS Rise to Output Disable	tTC	C <sub>LOAD</sub> = 20pF, Figure 1	20		100	ns

## TIMING CHARACTERISTICS (continued)

 $(V_{DD} = V_{LOGIC} = +2.7V \text{ to } +3.6V, \text{COM} = \text{GND}, \text{REFADJ} = V_{DD}, V_{REF} = +2.5V, 4.7\mu\text{F} \text{ capacitor at REF pin, } f_{CLK} = 4.8MHz (50\% \text{ duty cycle}), T_A = T_{MIN} \text{ to } T_{MAX}$ , unless otherwise noted. Typical values are at T\_A = +25°C.)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
RD Rise to Output Disable	t <sub>TR</sub>	$C_{LOAD} = 20 pF$ , Figure 1	20		70	ns
RD Fall to Output Data Valid	tDO	$C_{LOAD} = 20 pF$ , Figure 1	20		70	ns
HBEN to Output Data Valid	t <sub>DO1</sub>	C <sub>LOAD</sub> = 20pF, Figure 1	20		110	ns
RD Fall to INT High Delay	tint1	$C_{LOAD} = 20 pF$ , Figure 1			100	ns
CS Fall to Output Data Valid	tDO2	C <sub>LOAD</sub> = 20pF, Figure 1			110	ns

**Note 1:** Tested at  $V_{DD}$  = +3V, COM = GND, unipolar single-ended input mode.

Note 2: Relative accuracy is the deviation of the analog value at any code from its theoretical value after offset and gain errors have been removed.

Note 3: Offset nulled.

Note 4: On channel is grounded; sine wave applied to off channels.

Note 5: Conversion time is defined as the number of clock cycles times the clock period; clock has 50% duty cycle.

**Note 6:** Input voltage range referenced to negative input. The absolute range for the analog inputs is from GND to V<sub>DD</sub>.

Note 7: External load should not change during conversion for specified accuracy.

Note 8: When bit 5 is set low for internal acquisition, WR must not return low until after the first falling clock edge of the conversion.

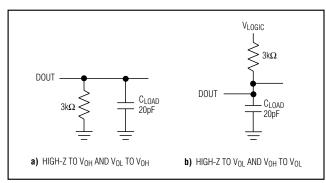
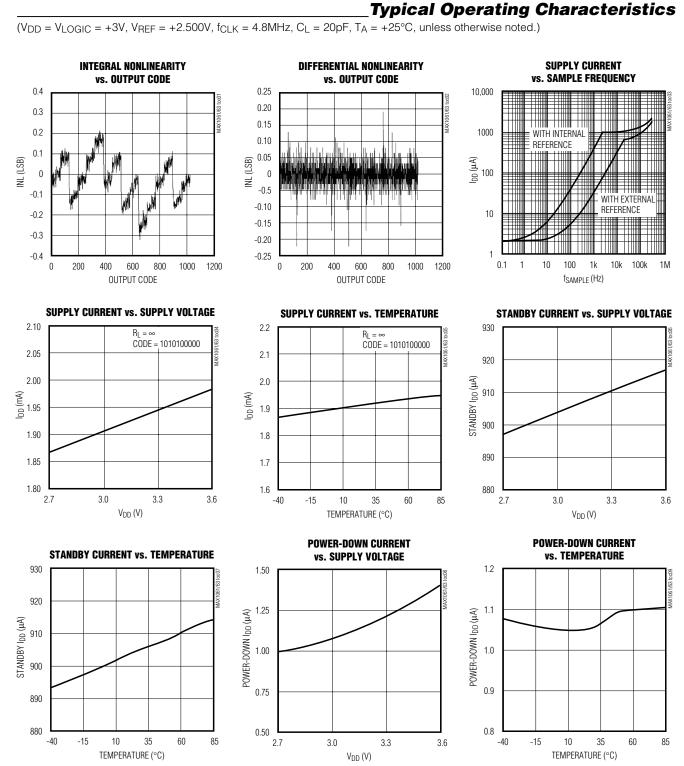
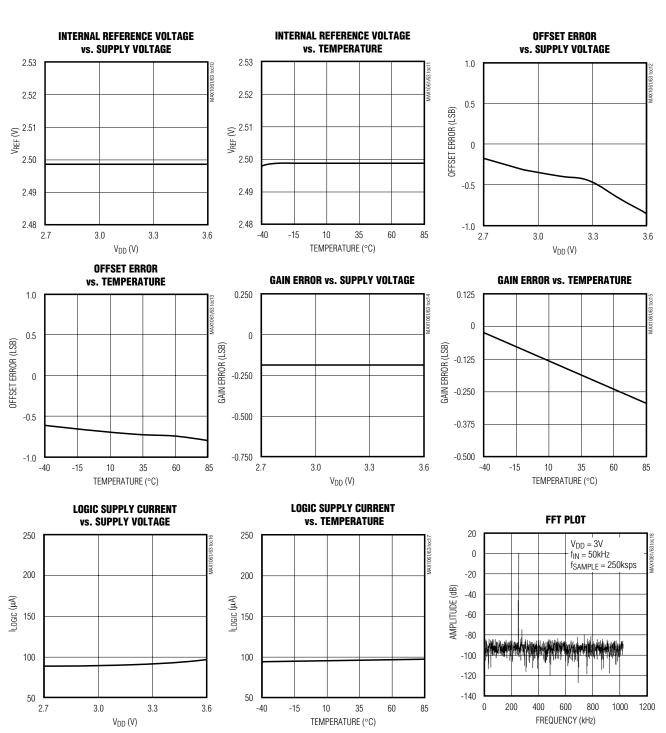


Figure 1. Load Circuits for Enable/Disable Times



MAX1061/MAX1063

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Typical Operating Characteristics (continued)

 $(V_{DD} = V_{LOGIC} = +3V, V_{REF} = +2.500V, f_{CLK} = 4.8MHz, C_L = 20pF, T_A = +25^{\circ}C, unless otherwise noted.)$ 

MAX1061/MAX1063

## **Pin Description**

PIN		NAME	FUNCTION
MAX1061	(1061 MAX1063		FUNCTION
1	1	HBEN	High Byte Enable. Used to multiplex the 10-bit conversion result: 1: 2 MSBs are multiplexed on the data bus. 0: 8 LSBs are available on the data bus.
2	2	D7	Tri-State Digital I/O Line (D7)
3	3	D6	Tri-State Digital I/O Line (D6)
4	4	D5	Tri-State Digital I/O Line (D5)
5	5	D4	Tri-State Digital I/O Line (D4)
6	6	D3	Tri-State Digital I/O Line (D3)
7	7	D2	Tri-State Digital I/O Line (D2)
8	8	D1/D9	Tri-State Digital I/O Line (D1, HBEN = 0; D9, HBEN = 1)
9	9	D0/D8	Tri-State Digital I/O Line (D0, HBEN = 0; D8, HBEN = 1)
10	10	ĪNT	INT goes low when the conversion is complete and the output data is ready.
11	11	RD	Active-Low Read Select. If $\overline{CS}$ is low, a falling edge on $\overline{RD}$ enables the read operation on the data bus.
12	12 12 Interview		Active-Low Write Select. When $\overline{CS}$ is low in internal acquisition mode, a rising edge on $\overline{WR}$ latches in configuration data and starts an acquisition plus a conversion cycle. When $\overline{CS}$ is low in external acquisition mode, the first rising edge on $\overline{WR}$ ends acquisition and starts a conversion.
13	13	CLK	Clock Input. In external clock mode, drive CLK with a TTL-/CMOS-compatible clock. In internal clock mode, connect this pin to either V <sub>DD</sub> or GND.
14	14	CS	Active-Low Chip Select. When $\overline{CS}$ is high, digital outputs (D7–D0) are high impedance.
15	_	CH7	Analog Input Channel 7
16	_	CH6	Analog Input Channel 6
17	_	CH5	Analog Input Channel 5
18	_	CH4	Analog Input Channel 4
19	15	СНЗ	Analog Input Channel 3
20	16	CH2	Analog Input Channel 2
21	17	CH1	Analog Input Channel 1
22	18	СНО	Analog Input Channel 0
23	19	СОМ	Ground Reference for Analog Inputs. Sets zero-code voltage in single-ended mode and must be stable to ±0.5 LSB during conversion.
24	20	GND	Analog and Digital Ground
25	21	REFADJ	Bandgap Reference Output/Bandgap Reference Buffer Input. Bypass to GND with a 0.01µF capacitor. When using an external reference, connect REFADJ to V <sub>DD</sub> to disable the internal bandgap reference.
26	22	REF	Bandgap Reference Buffer Output/External Reference Input. Add a 4.7µF capacitor to GND when using the internal reference.
27	23	V <sub>DD</sub>	Analog +5V Power Supply. Bypass with a 0.1µF capacitor to GND.
28	24	VLOGIC	Digital Power Supply. $V_{LOGIC}$ powers the digital outputs of the data converter and can range from +1.8V to (VDD + 300mV).



## **Detailed Description**

## **Converter Operation**

The MAX1061/MAX1063 ADCs use a successiveapproximation (SAR) conversion technique and an input track/hold (T/H) stage to convert an analog input signal to a 10-bit digital output. Their parallel (8 + 2) output format provides an easy interface to standard microprocessors ( $\mu$ Ps). Figure 2 shows the simplified internal architecture of the MAX1061/MAX1063.

#### Single-Ended and Pseudo-Differential Operation

The sampling architecture of the ADC's analog comparator is illustrated in the equivalent input circuit in Figure 3. In single-ended mode, IN+ is internally switched to channels CH0-CH7 for the MAX1061 (Figure 3a) and to CH0-CH3 for the MAX1063 (Figure 3b), while IN- is switched to COM (Table 3).

In differential mode, IN+ and IN- are selected from analog input pairs (Table 4) and are internally switched to either of the analog inputs. This configuration is pseudodifferential in that only the signal at IN+ is sampled. The return side (IN-) must remain stable within  $\pm 0.5$  LSB ( $\pm 0.1$  LSB for best performance) with respect to GND during a conversion. To accomplish this, connect a 0.1µF capacitor from IN- (the selected input) to GND.

During the acquisition interval, the channel selected as the positive input (IN+) charges capacitor  $C_{HOLD}$ . At the end of the acquisition interval, the T/H switch opens, retaining charge on  $C_{HOLD}$  as a sample of the signal at IN+.

The conversion interval begins with the input multiplexer switching C<sub>HOLD</sub> from the positive input (IN+) to the negative input (IN-). This unbalances node zero at the comparator's positive input. The capacitive digital-to-analog converter (DAC) adjusts during the remainder of the conversion cycle to restore node 0 to 0V within the limits of 10-bit resolution. This action is equivalent to transferring a 12pF[(VIN+) - (VIN-)] charge from C<sub>HOLD</sub> to the binary-weighted capacitive DAC, which in turn forms a digital representation of the analog input signal.

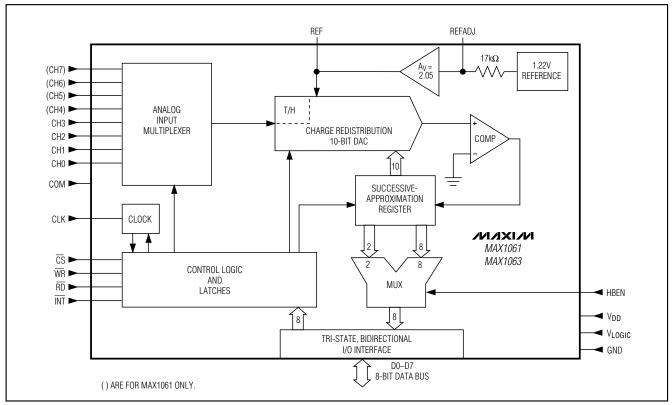


Figure 2. Simplified Internal Architecture for 8-/4-Channel MAX1061/MAX1063

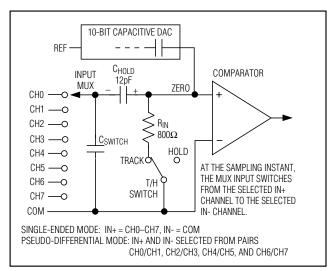


Figure 3a. MAX1061 Simplified Input Structure

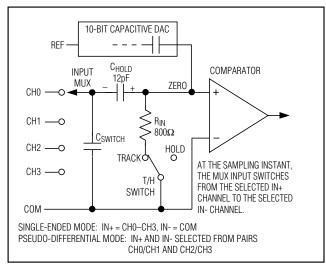


Figure 3b. MAX1063 Simplified Input Structure

## **Analog Input Protection**

Internal protection diodes, which clamp the analog input to V<sub>DD</sub> and GND, allow each input channel to swing within (GND - 300mV) to (V<sub>DD</sub> + 300mV) without damage. However, for accurate conversions near full scale, both inputs must not exceed (V<sub>DD</sub> + 50mV) or be less than (GND - 50mV).

If an off-channel analog input voltage exceeds the supplies by more than 50mV, limit the forward-bias input current to 4mA.

## Track/Hold

The MAX1061/MAX1063 T/H stage enters its tracking mode on the rising edge of  $\overline{\text{WR}}$ . In external acquisition mode, the part enters its hold mode on the next rising edge of  $\overline{\text{WR}}$ . In internal acquisition mode, the part enters its hold mode on the fourth falling edge of clock after writing the control byte. Note that, in internal clock mode, this occurs approximately 1µs after writing the control byte. In single-ended operation, IN- is connected to COM and the converter samples the positive (+) input. In pseudo-differential operation, IN- connects to the negative input (-), and the difference of |(IN+) - (IN-)| is sampled. At the beginning of the next conversion, the positive input connects back to IN+ and CHOLD charges to the input signal.

The time required for the T/H stage to acquire an input signal depends on how quickly its input capacitance is charged. If the input signal's source impedance is high, the acquisition time lengthens, and more time must be allowed between conversions. The acquisition time,  $t_{ACQ}$ , is the maximum time the device takes to acquire the signal and is also the minimum time required for the signal to be acquired. Calculate this with the following equation:

#### $t_{ACQ} = 7(R_S + R_{IN})C_{IN}$

where Rs is the source impedance of the input signal, R<sub>IN</sub> (800 $\Omega$ ) is the input resistance, and C<sub>IN</sub> (12pF) is the ADC's input capacitance. Source impedances below 3k $\Omega$  have no significant impact on the MAX1061/MAX1063s' AC performance.

Higher source impedances can be used if a  $0.01\mu$ F capacitor is connected to the individual analog inputs. Together with the input impedance, this capacitor forms an RC filter, limiting the ADC's signal bandwidth.

#### Input Bandwidth

The MAX1061/MAX1063 T/H stage offers a 250kHz fulllinear and a 3MHz full-power bandwidth, enabling these parts to use undersampling techniques to digitize high-speed transients and measure periodic signals with bandwidths exceeding the ADC's sampling rate. To avoid high-frequency signals being aliased into the frequency band of interest, anti-alias filtering is recommended.

#### **Starting a Conversion**

Initiate a conversion by writing a control byte that selects the multiplexer channel and configures the MAX1061/MAX1063 for either unipolar or bipolar operation. A write pulse ( $\overline{WR} + \overline{CS}$ ) can either start an acquisition interval or initiate a combined acquisition plus

MAX1061/MAX1063

conversion. The sampling interval occurs at the end of the acquisition interval. The ACQMOD (acquisition mode) bit in the input control byte (Table 1) offers two options for acquiring the signal: an internal and an external acquisition. The conversion period lasts for 13 clock cycles in either the internal or external clock or acquisition mode. Writing a new control byte during a conversion cycle aborts the conversion and starts a new acquisition interval.

#### Internal Acquisition

Select internal acquisition by writing the control byte with the ACQMOD bit cleared (ACQMOD = 0). This causes the write pulse to initiate an acquisition interval whose duration is internally timed. Conversion starts when this acquisition interval ends (three external cycles or approximately 1 $\mu$ s in internal clock mode) (Figure 4). Note that, when the internal acquisition is combined with the internal clock, the aperture jitter can be as high as 200ps. Internal clock users wishing to achieve the 50ps jitter specification should always use external acquisition mode.

#### External Acquisition

Use external acquisition mode for precise control of the sampling aperture and/or dependent control of acquisition and conversion times. The user controls acquisition and start of conversion with two separate write pulses. The first pulse, written with ACQMOD = 1, starts an acquisition interval of indeterminate length. The second write pulse, written with ACQMOD = 0, terminates acquisition and starts conversion on WR's rising edge (Figure 5).

The address bits for the input multiplexer must have the same values on the first and second write pulse. Power-down mode bits (PD0, PD1) can assume new values on the second write pulse (see the *Power-Down Modes* section). Changing other bits in the control byte corrupts the conversion.

#### **Reading a Conversion**

A standard interrupt signal,  $\overline{INT}$ , is provided to allow the MAX1061/MAX1063 to flag the  $\mu$ P when the conversion has ended and a valid result is available.  $\overline{INT}$  goes low when the conversion is complete and the output data is ready (Figures 4 and 5). It returns high on the first read cycle or if a new control byte is written.

BIT	NAME		FUNCTION						
		PD1 ar	nd <b>PD0</b> s	elect the various clock and power-down modes.					
		0	0	Full power-down mode. Clock mode is unaffected.					
D7, D6	PD1, PD0	0	1	Standby power-down mode. Clock mode is unaffected.					
		1 0		Normal operation mode. Internal clock mode selected.					
		1	1	Normal operation mode. External clock mode selected.					
D5	ACQMOD		ACQMOD = 0: Internal acquisition mode ACQMOD = 1: External acquisition mode						
D4	SGL/DIF	SGL/Ē In sing	SGL/DIF = 0: Pseudo-differential analog input mode SGL/DIF = 1: Single-ended analog input mode In single-ended mode, input signals are referred to COM. In pseudo-differential mode, the voltage difference between two channels is measured (Tables 2 and 3).						
D3	UNI/BIP	UNI/B In unip	$UNI/\overline{BIP} = 0$ : Bipolar mode $UNI/\overline{BIP} = 1$ : Unipolar mode In unipolar mode, an analog input signal from 0 to V <sub>REF</sub> can be converted; in bipolar mode, the sig- nal can range from -V <sub>REF</sub> /2 to +V <sub>REF</sub> /2.						
D2, D1, D0	A2, A1, A0		Address bits A2, A1, A0 select which of the 8/4 (MAX1061/MAX1063) channels are to be converted (Tables 3 and 4).						

## Table 1. Control Byte Functional Description

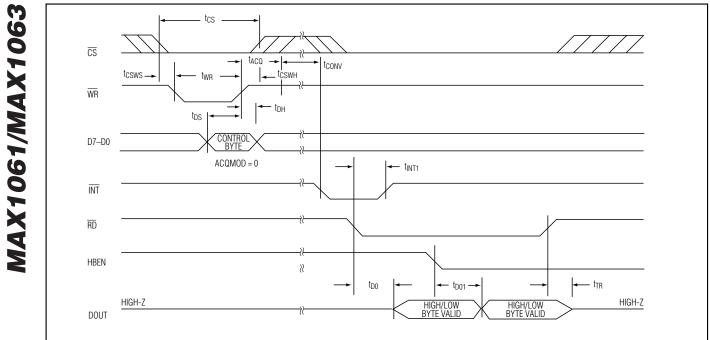


Figure 4. Conversion Timing Using Internal Acquisition Mode

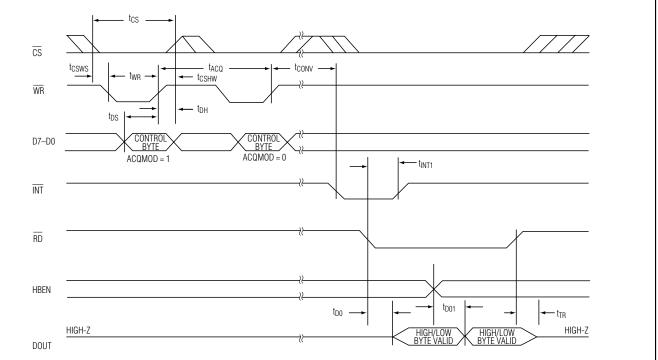


Figure 5. Conversion Timing Using External Acquisition Mode

#### **Selecting Clock Mode**

The MAX1061/MAX1063 operate with either an internal or an external clock. Control bits D6 and D7 select either internal or external clock mode. The parts retain the last-requested clock mode if a power-down mode is selected in the current input word. For both internal and external clock modes, internal or external acquisition can be used. At power-up, the MAX1061/MAX1063 enter the default external clock mode.

#### Internal Clock Mode

Select internal clock mode to release the  $\mu$ P from the burden of running the SAR conversion clock. To select this mode, bit D7 of the control byte must be set to 1 and D6 must be set to zero. The internal clock frequency is then selected, resulting in a conversion time of 3.6 $\mu$ s. When using the internal clock mode, tie the CLK pin either high or low to prevent the pin from floating.

#### External Clock Mode

To select the external clock mode, bits D6 and D7 of the control byte must be set to 1. Figure 6 shows the clock and WR timing relationship for internal (Figure 6a) and external (Figure 6b) acquisition modes with an external clock. For proper operation, a 100kHz to 4.8MHz clock frequency with 30% to 70% duty cycle is recommended. Operating the MAX1061/MAX1063 with clock frequencies lower than 100kHz is not recommended, because it causes a voltage droop across the hold capacitor in the T/H stage that results in degraded performance.

## **Digital Interface**

Input (control byte) and output data are multiplexed on a tri-state parallel interface. This parallel interface (I/O) can easily be interfaced with standard  $\mu$ Ps. The signals  $\overline{CS}$ , WR, and  $\overline{RD}$  control the write and read operations.  $\overline{CS}$  represents the chip-select signal, which enables a  $\mu$ P to address the MAX1061/MAX1063 as an I/O port. When high,  $\overline{CS}$  disables the CLK,  $\overline{WR}$ , and  $\overline{RD}$  inputs and forces the interface into a high-impedance (high-Z) state.

#### Input Format

The control byte is latched into the device on pins D7–D0 during a write command. Table 2 shows the control byte format.

#### **Output Format**

The output format for both the MAX1061/MAX1063 is binary in unipolar mode and two's complement in bipolar mode. When reading the output data,  $\overline{CS}$  and  $\overline{RD}$ must be low. When HBEN = 0, the lower 8 bits are read. With HBEN = 1, the upper 2 bits are available and the output data bits D7–D2 are set either low in unipolar mode or set to the value of the MSB in bipolar mode (Table 5).

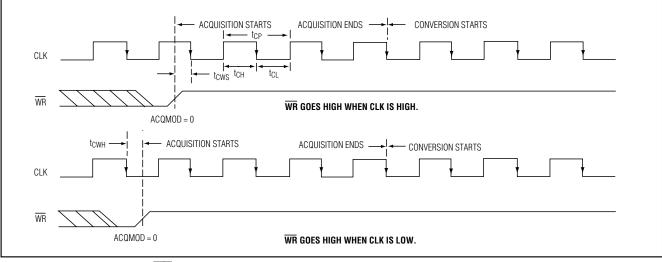


Figure 6a. External Clock and WR Timing (Internal Acquisition Mode)

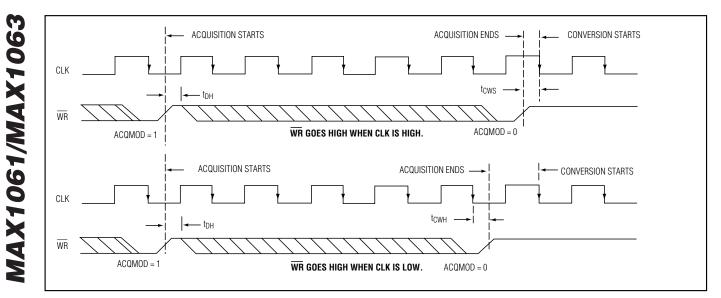


Figure 6b. External Clock and WR Timing (External Acquisition Mode)

## **Table 2. Control Byte Format**

D7 (MSB)	D6	D5	D4	D3	D2	D1	D0 (LSB)
PD1	PD0	ACQMOD	SGL/DIF	UNI/BIP	A2	A1	AO

## Table 3. Channel Selection for Single-Ended Operation (SGL/DIF = 1)

A2	A1	A0	CH0	CH1	CH2	СНЗ	CH4*	CH5*	CH6*	CH7*	СОМ
0	0	0	+								-
0	0	1		+							-
0	1	0			+						-
0	1	1				+					-
1	0	0					+				-
1	0	1						+			-
1	1	0							+		-
1	1	1								+	-

\*Channels CH4–CH7 apply to MAX1061 only.

## Table 4. Channel Selection for Pseudo-Differential Operation (SGL/DIF = 0)

A2	A1	A0	CH0	CH1	CH2	СНЗ	CH4*	CH5*	CH6*	CH7*
0	0	0	+	-						
0	0	1	-	+						
0	1	0			+	-				
0	1	1			-	+				
1	0	0					+	-		
1	0	1					-	+		
1	1	0							+	-
1	1	1							-	+

\*Channels CH4–CH7 apply to MAX1061 only.

## Applications Information

## **Power-On Reset**

When power is first applied, internal power-on reset circuitry activates the MAX1061/MAX1063 in external clock mode and sets  $\overline{INT}$  high. After the power supplies stabilize, the internal reset time is 10µs, and no conversions should be attempted during this phase. When using the internal reference, 500µs are required for VREF to stabilize.

## **Internal and External Reference**

The MAX1061/MAX1063 can be used with an internal or external reference voltage. An external reference can be connected directly to REF or REFADJ.

An internal buffer is designed to provide +2.5V at REF for both the MAX1061 and the MAX1063. The internally trimmed +1.22V reference is buffered with a +2.05V/V gain.

# Table 5. Data-Bus Output (8 + 2 ParallelInterface)

PIN	HBEN = 0	HBEN = 1				
D0	Bit 0 (LSB)	Bi	t 8			
D1	Bit 1	Bit 9 (	MSB)			
		BIPOLAR (UNI/BIP = 0)	UNIPOLAR (UNI/BIP = 1)			
D2	Bit 2	Bit 9	0			
D3	Bit 3	Bit 9	0			
D4	Bit 4	Bit 9	0			
D5	Bit 5	Bit 9	0			
D6	Bit 6	Bit 9	0			
D7	Bit 7	Bit 9	0			

#### Internal Reference

With the internal reference, the full-scale range is  $\pm 2.5V$  with unipolar inputs and  $\pm 1.25V$  with bipolar inputs. The internal reference buffer allows for small adjustments ( $\pm 100$ mV) in the reference voltage (Figure 7).

**Note:** The reference buffer must be compensated with an external capacitor ( $4.7\mu$ F min) connected between REF and GND to reduce reference noise and switching spikes from the ADC. To further minimize noise on the reference, connect a  $0.01\mu$ F capacitor between REFADJ and GND.

#### External Reference

With both the MAX1061 and MAX1063, an external reference can be placed at either the input (REFADJ) or the output (REF) of the internal reference buffer amplifier.

Using the REFADJ input makes buffering the external reference unnecessary. The REFADJ input impedance is typically  $17k\Omega$ .

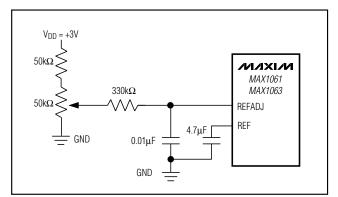


Figure 7. Reference Voltage Adjustment with External Potentiometer

When applying an external reference to REF, disable the internal reference buffer by connecting REFADJ to V<sub>DD</sub>. The DC input resistance at REF is  $25k\Omega$ . Therefore, an external reference at REF must deliver up to  $200\mu$ A DC load current during a conversion and have an output impedance less than  $10\Omega$ . If the reference has higher output impedance or is noisy, bypass it close to the REF pin with a  $4.7\mu$ F capacitor.

#### **Power-Down Modes**

Save power by placing the converter in a low-current shutdown state between conversions. Select standby mode or shutdown mode using bits D6 and D7 of the control byte (Tables 1 and 2). In both software powerdown modes, the parallel interface remains active, but the ADC does not convert.

While in standby mode, the supply current is 850µA (typ). The part powers up on the next rising edge on WR and is ready to perform conversions. This quick turn-on time allows the user to realize significantly reduced power consumption for conversion rates below 250ksps.

**Shutdown Mode** Shutdown mode turns off all chip functions that draw quiescent current, reducing the typical supply current to 2µA immediately after the current conversion is complet-

OUTPUT CODE FULL-SCALE TRANSITION 111 . . . 111 FS = REF + COM111 . . . 110 7S = COM $1 \text{ LSB} = \frac{\text{REF}}{1024}$ 100...010 100 . . . 001 100...000 011 . . . 111 011 . . . 110 011 . . . 101 000...001 000 . . . 000 0 512 FS

INPUT VOLTAGE (LSB) FS - 3/2 LSB

Figure 8. Unipolar Transfer Function

(COM)

#### Standby Mode

mode, can reduce power consumption by a factor of 3 or more. When using an external reference, only 50µs is required after power-up. Enter standby mode by performing a dummy conversion with the control byte specifying standby mode. **Note:** Bypassing capacitors larger than 4.7µF between REF and GND results in longer power-up delays.

ed. A rising edge on WR causes the MAX1061/MAX1063

to exit shutdown mode and return to normal operation.

To achieve full 10-bit accuracy with a 4.7µF reference

bypass capacitor, 500µs is required after power-up.

Waiting 500µs in standby mode, instead of in full-power

## **Transfer Function**

Table 6 shows the full-scale voltage ranges for unipolar and bipolar modes.

Figure 8 depicts the nominal, unipolar input/output (I/O) transfer function and Figure 9 shows the bipolar I/O transfer function. Code transitions occur halfway between successive-integer LSB values. Output coding is binary, with 1 LSB =  $V_{REF}$  / 1024.

#### Maximum Sampling Rate/ Achieving 300ksps

When running at the maximum clock frequency of 4.8MHz, the specified throughput of 250ksps is achieved by completing a conversion every 19 clock cycles: 1 write cycle, 3 acquisition cycles, 13 conver-

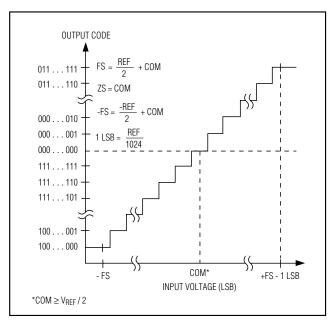


Figure 9. Bipolar Transfer Function

Table 6. Full Scale and Zero Scale for Unipolar and Bipolar Operation
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UNIPOL	AR MODE	BIPOLAR MODE			
Full scale	V <sub>REF</sub> + COM	Positive full scale	V <sub>REF</sub> /2 + COM		
Zero scale	СОМ	Zero scale	СОМ		
	_	Negative full scale	-V <sub>REF</sub> /2 + COM		

MAX1061/MAX1063 **Differential Nonlinearity** Differential nonlinearity (DNL) is the difference between an actual step width and the ideal value of 1 LSB. A DNL error specification of less than 1 LSB guarantees **Aperture Definitions** Aperture jitter (t<sub>A,J</sub>) is the sample-to-sample variation in the time between the samples. Aperture delay (t<sub>AD</sub>) is the time between the rising edge of the sampling clock

## Layout, Grounding, and Bypassing

For best performance, use printed circuit (PC) boards. Wire-wrap configurations are not recommended since the layout should ensure proper separation of analog and digital traces. Do not run analog and digital lines parallel to each other, and do not lay out digital signal paths underneath the ADC package. Use separate analog and digital PC board ground sections with only one star point (Figure 11) connecting the two ground systems (analog and digital). For lowest noise operation, ensure the ground return to the star ground's power supply is low impedance and as short as possible. Route digital signals far away from sensitive analog and reference inputs.

sion cycles, and 2 read cycles. This assumes that the

results of the last conversion are read before the next

control byte is written. Throughputs up to 300ksps can

be achieved by first writing a control word to begin the

acquisition cycle of the next conversion, then reading

the results of the previous conversion from the bus

(Figure 10). This technique allows a conversion to be

completed every 16 clock cycles. Note that the switch-

ing of the data bus during acquisition or conversion

can cause additional supply noise, which can make it

difficult to achieve true 10-bit performance.

High-frequency noise in the power supply (VDD) could influence the proper operation of the ADC's fast comparator. Bypass VDD to the star ground with a network of two parallel capacitors, 0.1µF and 4.7µF, located as close as possible to the MAX1061/MAX1063s' powersupply pin. Minimize capacitor lead length for best supply-noise rejection; add an attenuation resistor (5 $\Omega$ ) if the power supply is extremely noisy.

## Definitions

## Integral Nonlinearity

Integral nonlinearity (INL) is the deviation of the values on an actual transfer function from a straight line. This straight line can be either a best-straight-line fit or a line drawn between the end points of the transfer function, once offset and gain errors have been nullified. The static linearity parameters for the MAX1061/MAX1063 are measured using the end-point method.

## and the instant when an actual sample is taken.

## Signal-to-Noise Ratio

For a waveform perfectly reconstructed from digital samples, signal-to-noise ratio (SNR) is the ratio of the full-scale analog input (RMS value) to the RMS quantization error (residual error). The ideal, theoretical minimum analog-to-digital noise is caused by quantization error only and results directly from the ADC's resolution (N bits):

no missing codes and a monotonic transfer function.

## $SNR = (6.02 \times N + 1.76) dB$

In reality, there are other noise sources besides quantization noise: thermal noise, reference noise, clock jitter, etc. Therefore, SNR is computed by taking the ratio of the RMS signal to the RMS noise, which includes all spectral components minus the fundamental, the first five harmonics, and the DC offset.

## Signal-to-Noise Plus Distortion

Signal-to-noise plus distortion (SINAD) is the ratio of the fundamental input frequency's RMS amplitude to the RMS equivalent of all other ADC output signals:

 $SINAD (dB) = 20 \times log (Signal_{RMS} / Noise_{RMS})$ 

## **Effective Number of Bits**

Effective number of bits (ENOB) indicates the global accuracy of an ADC at a specific input frequency and sampling rate. An ideal ADC error consists of quantization noise only. With an input range equal to the fullscale range of the ADC, calculate the effective number of bits as follows:



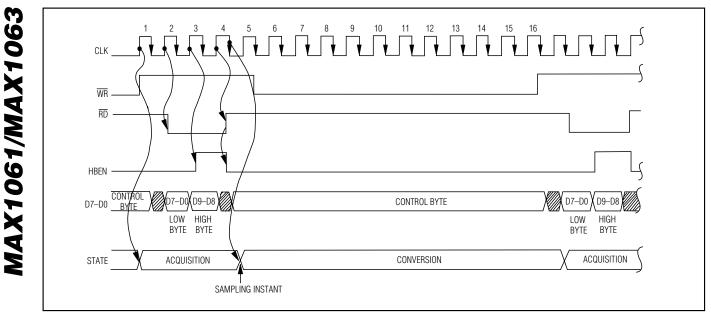


Figure 10. Timing Diagram for Fastest Conversion

#### **Total Harmonic Distortion**

Total harmonic distortion (THD) is the ratio of the RMS sum of the first five harmonics of the input signal to the fundamental itself. This is expressed as:

THD = 
$$20 \times \log \left( \sqrt{\left( V_2^2 + V_3^2 + V_4^2 + V_5^2 \right)} / V_1 \right)$$

where  $V_1$  is the fundamental amplitude, and  $V_2$  through  $V_5$  are the amplitudes of the 2nd- through 5th-order harmonics.

## **Spurious-Free Dynamic Range**

Spurious-free dynamic range (SFDR) is the ratio of the RMS amplitude of the fundamental (maximum signal component) to the RMS value of the next-largest distortion component.

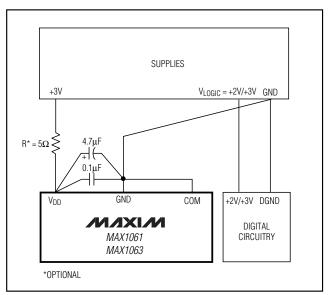
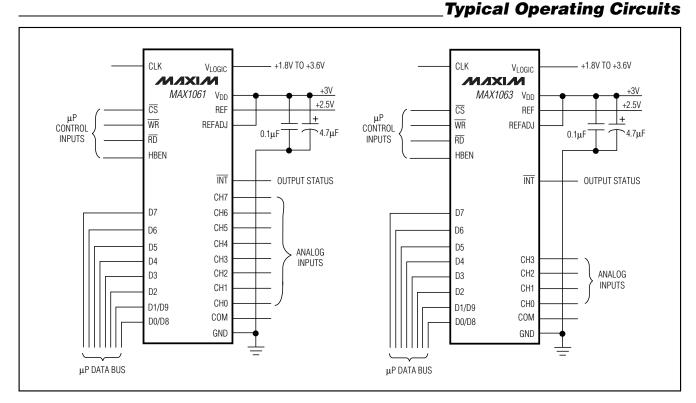
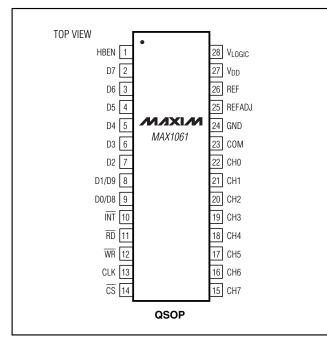


Figure 11. Power-Supply and Grounding Connections

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## Pin Configurations (continued)



## \_\_Ordering Information (continued)

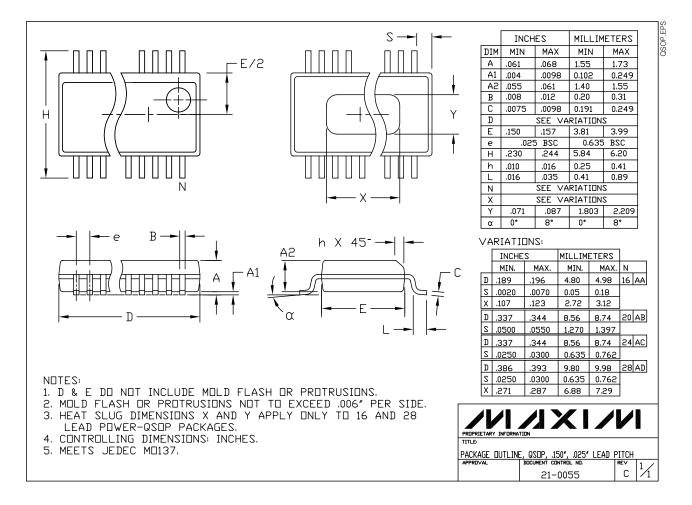
PART	TEMP RANGE	PIN-PACKAGE	INL (LSB)
MAX1063ACEG	0°C to +70°C	24 QSOP	±0.5
MAX1063BCEG	0°C to +70°C	24 QSOP	±1
MAX1063AEEG	-40°C to +85°C	24 QSOP	±0.5
MAX1063BEEG	-40°C to +85°C	24 QSOP	±1

## **Chip Information**

TRANSISTOR COUNT: 5781

## **Package Information**

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <u>www.maxim-ic.com/packages</u>.)



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